Double-Balanced Mixer
5 - 20 GHz

MAMX-011067
Rev. V1

Features

- Low Conversion Loss: 6 dB
- Wide IF Bandwidth: DC to 6 GHz
- IIP3 +21 dBm @ 15 dBm LO Drive
- High Isolation
- Lead-Free 3 mm 12-lead QFN Package
- RoHS* Compliant

Applications

- Test & Measurement
- Microwave Radio
- Radar

Description

MAMX-011067 is a GaAs double-balanced passive diode mixer housed in a lead-free 3 mm, 12-lead QFN package. The mixer offers low conversion loss, high linearity and a wide IF bandwidth. The double-balanced circuit configuration provides excellent port isolation while internal 50 Ω matching simplifies its application.

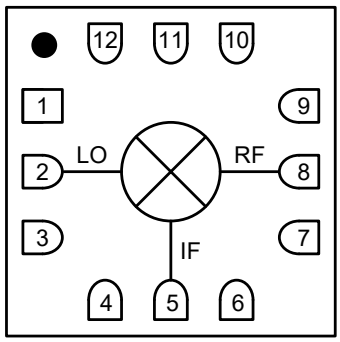
This mixer is well suited for applications such as test and measurement, microwave radio and radar.

Ordering Information[1,2]

Part Number	Package
MAMX-011067	Bulk
MAMX-011067-TR0500	500 Piece Reel[1]
MAMX-011067-SB1	Sample Board[2]

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

Functional Schematic



Pin Configuration

Pin #	Function
1,3,4,6,7,9	GND
2	LO
5	IF
8	RF
10 - 12	NC[3]
13	GND[4]

3. MACOM recommends connecting unused package pins to ground.
4. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

Electrical Specifications[5]: F_{IF} = 100 MHz, P_{LO} = 15 dBm, T_A = +25°C, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Typ.	Max.
LO and RF Frequency	—	GHz	5	—	20
IF Frequency	—	GHz	0	—	6
LO Power	—	dBm	—	15	—
Conversion Loss	5 - 20 GHz	dB	—	7	9
Input P1dB	5 - 10 GHz 10 - 20 GHz	dBm	—	8 11	—
Input IP3	P_{RF} = -10 dBm/tone, Δf = 1 MHz 5 - 10 GHz 10 - 20 GHz	dBm	—	 18 20	—
Input IP2	P_{RF} = -10 dBm/tone, Δf = 1 MHz 5 - 10 GHz 10 - 20 GHz	dBm	—	 45 45	—
LO-to-RF Isolation	5 - 10 GHz 10 - 20 GHz	dB	—	34 30	—
LO-to-IF Isolation	5 - 10 GHz 10 - 20 GHz	dB	25 28	35 40	—
RF-to-IF Isolation	5 - 10 GHz 10 - 20 GHz	dB	—	16 31	—

5. All specifications refer to down-conversion operation, unless otherwise noted.

Absolute Maximum Ratings[6,7]

Parameter	Absolute Maximum
LO Power	23 dBm
RF or IF Power	20 dBm
Junction Temperature[8]	+150°C
Operating Temperature	-55°C to +85°C
Storage Temperature	-65°C to +150°C

6. Exceeding any one or combination of these limits may cause permanent damage to this device.
7. MACOM does not recommend sustained operation near these survivability limits.
8. Operating at nominal conditions with $T_J \leq$ +150°C will ensure MTTF > 1 x 10^6 hours. Thermal resistance, Θ_{JC} is +85°C/W.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices with the following rating:

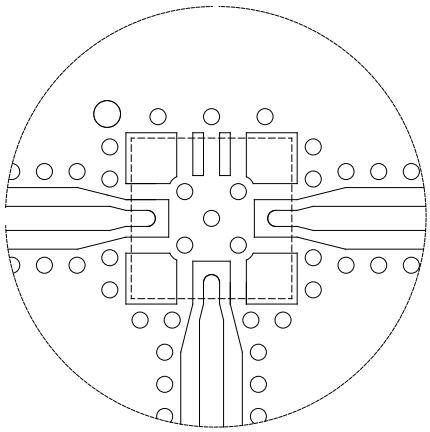
HBM Class 1B
CDM Class C3

MxN Spurious Rejection at IF Port (dBc IF)

RF = 10.1 GHz @ -10 dBm
LO = 10.0 GHz @ +15 dBm

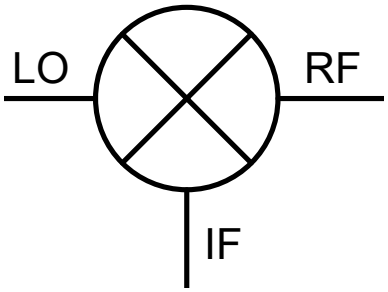
	nxLO				
mxRF	**0**	**1**	**2**	**3**	**4**
0	x	10	32	23	36
1	20	0	43	55	60
2	94	66	64	76	90
3	91	104	110	81	88
4	x	x	x	x	110

PCB Layout



DXF available on request based on 10 mil RO4350 substrate.

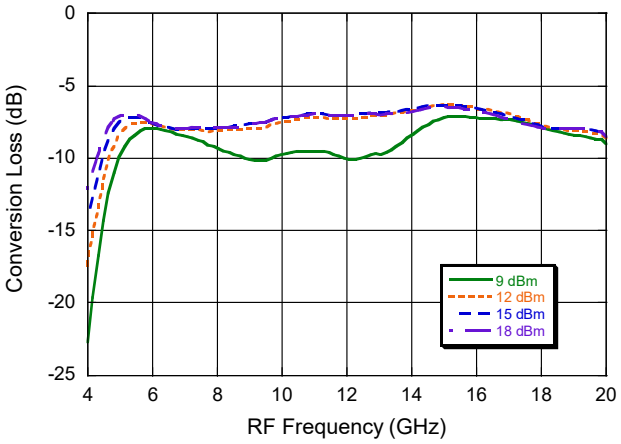
Application Schematic



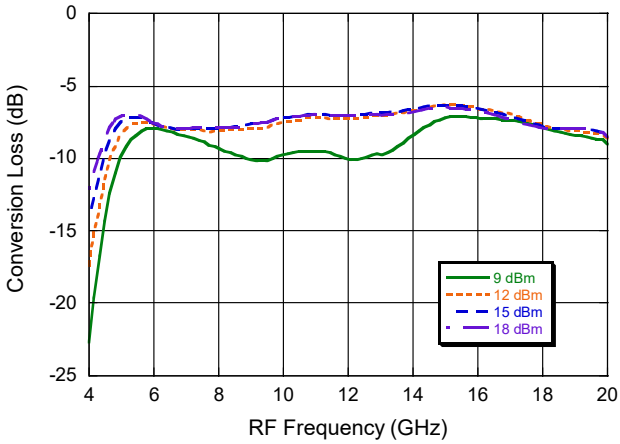
No external parts required for operation of MAMX-011067.

Typical Performance Curves

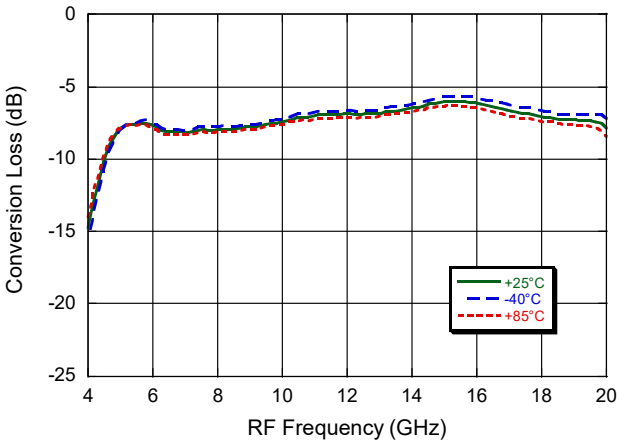
Conversion Loss USB (Down Conversion)
@ +25°C, I_F = 100 MHz



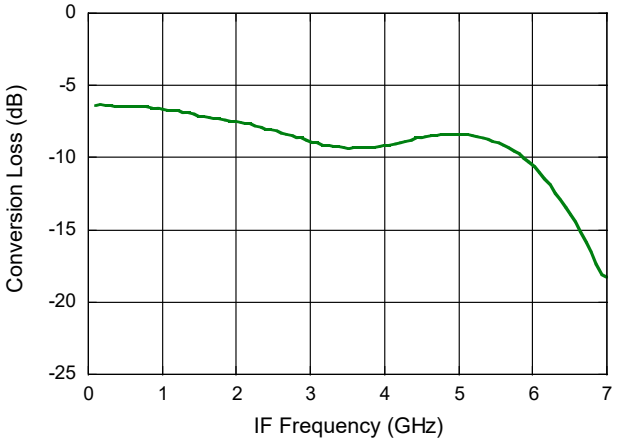
Conversion Loss USB (Up Conversion)
@ +25°C, I_F = 100 MHz



Conversion Loss
Over Temperature, I_F = 100 MHz

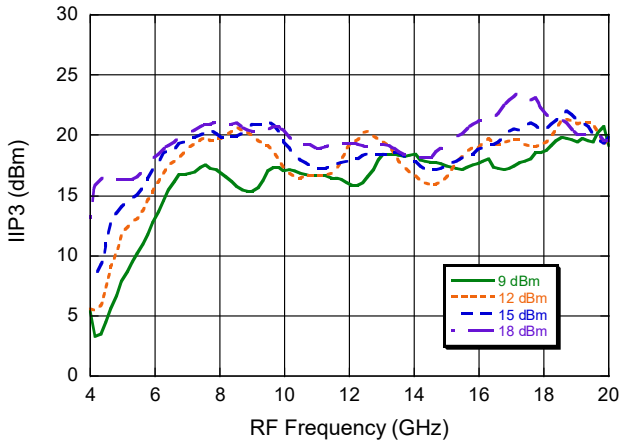


IF Bandwidth
@ +25°C, F_{LO} = 10 GHz, P_{LO} = 15 dBm

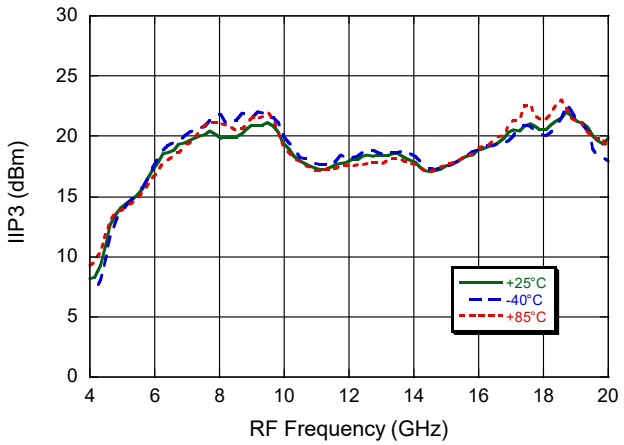


Typical Performance Curves

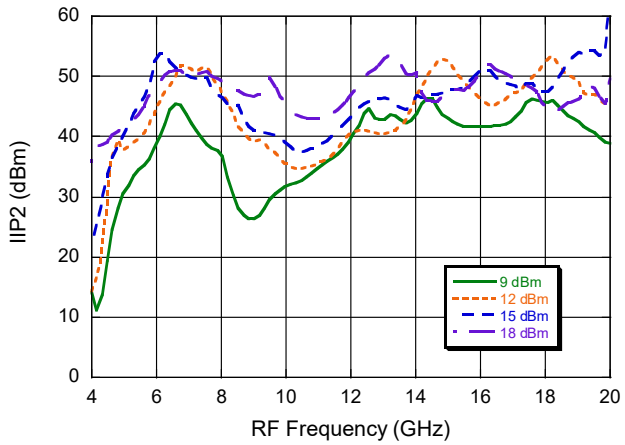
IIP3 @ LO Power, I_F = 100 MHz



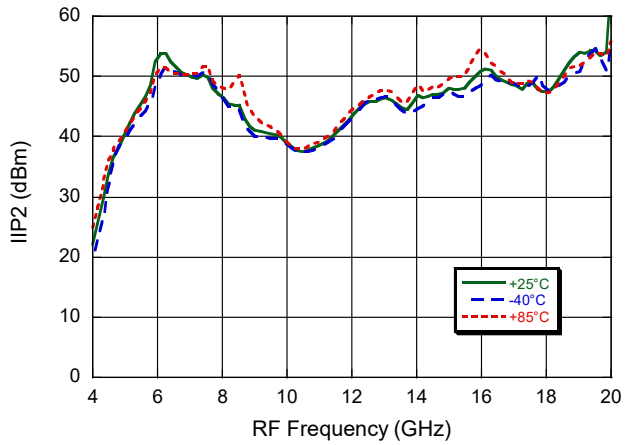
IIP3 over Temperature @ P_{LO} = 15 dBm, I_F = 100 MHz



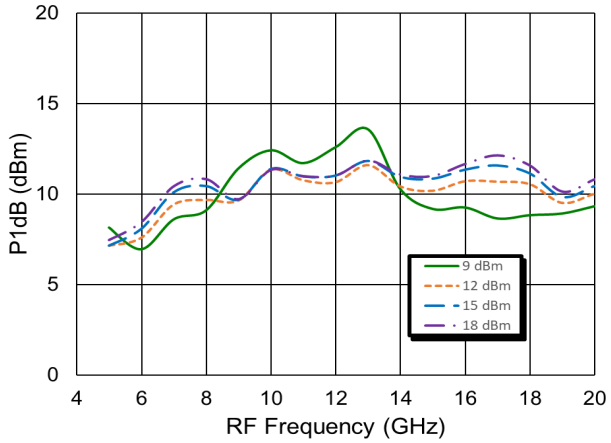
IIP2 @ LO Power, IF = 100 MHz



IIP2 over Temperature @ P_{LO} = 15 dBm, I_F = 100 MHz

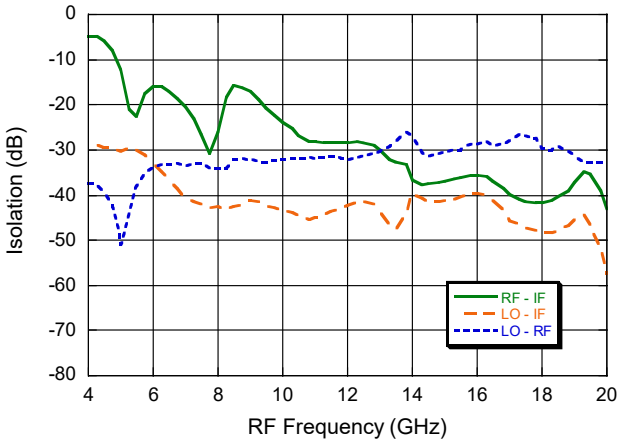


P1dB @ LO Power, I_F = 100 MHz

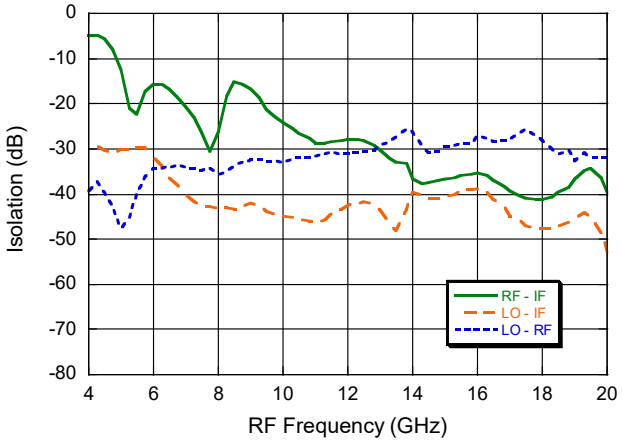


Typical Performance Curves

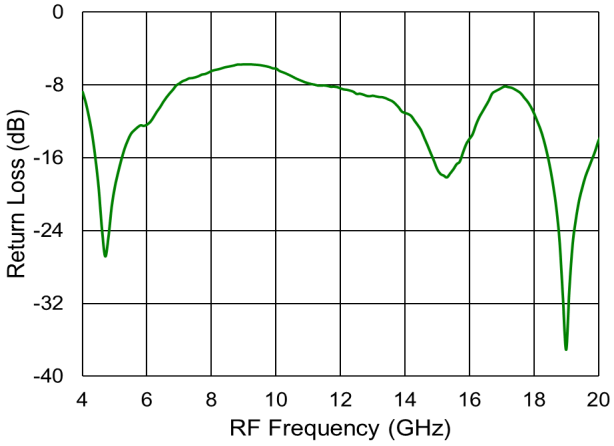
Isolation (Down Conversion)
@ IF = 100 MHz, P_{LO} = 15 dBm; P_{RF} = -10 dBm



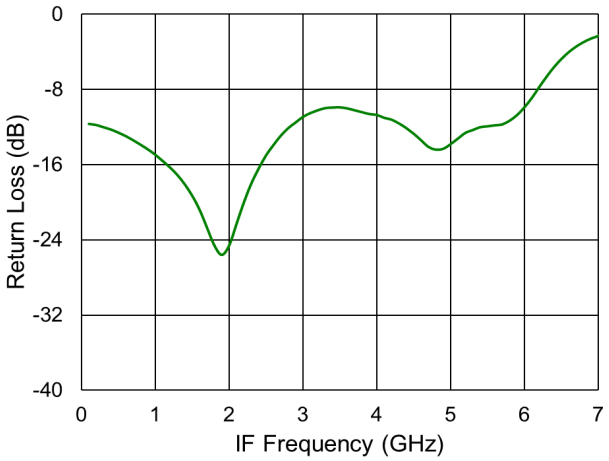
Isolation (Up Conversion)
@ IF = 100 MHz, P_{LO} = 15 dBm; P_{RF} = -10 dBm



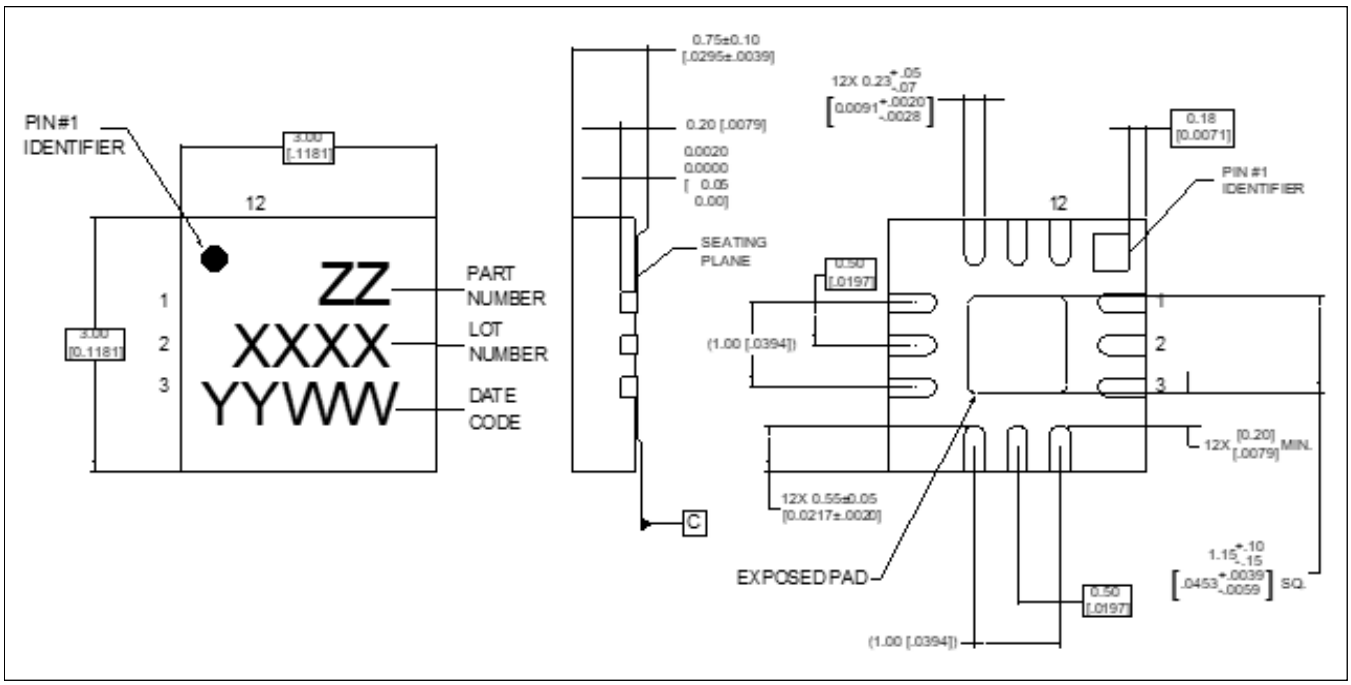
RF Return Loss
@ +25°C, F_{LO} = 10 GHz, P_{LO} = 15 dBm



IF Return Loss
@ +25°C, F_{LO} = 10 GHz, P_{LO} = 15 dBm



Lead-Free 3 mm 12-Lead QFN†



† Reference Application Note S2083 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is 100% matte tin over copper.